

# Recognition on systems RbF–GaF<sub>3</sub> and CsF–GaF<sub>3</sub>

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## Abstract

The systems RbF–GaF<sub>3</sub> and CsF–GaF<sub>3</sub> were re-investigated by DTA and XRD method. In the system RbF–GaF<sub>3</sub>, with eutectic E<sub>1</sub> at 750°C in the location of 8.5 mol% GaF<sub>3</sub> and E<sub>2</sub> at 749°C in the location of 43.0 mol% GaF<sub>3</sub>, three compounds Rb<sub>3</sub>GaF<sub>6</sub>, RbGaF<sub>4</sub> and RbF·2GaF<sub>3</sub> were identified and indexed by XRD. The indexed result of  $\alpha$ -Rb<sub>3</sub>GaF<sub>6</sub> could not be successfully obtained,  $\beta$ -Rb<sub>3</sub>GaF<sub>6</sub> is tetragonal,  $a = 6.324 \pm 0.004$ ,  $c = 8.860 \pm 0.003$  Å. RbGaF<sub>4</sub> is orthorhombic,  $a = 9.821 \pm 0.006$ ,  $b = 9.517 \pm 0.005$ ,  $c = 8.060 \pm 0.006$  Å; RbF·2GaF<sub>3</sub> is also orthorhombic,  $a = 9.459 \pm 0.005$ ,  $b = 9.336 \pm 0.005$ ,  $c = 7.685 \pm 0.005$  Å. In the system CsF–GaF<sub>3</sub>, with eutectic E<sub>1</sub> at 664°C in the location of 7.5 mol% GaF<sub>3</sub> and E<sub>2</sub> at 675°C in the position of 44.0 mol% GaF<sub>3</sub>, two compounds were confirmed.  $\alpha$ -Cs<sub>3</sub>GaF<sub>6</sub> is orthorhombic with  $a = 10.62 \pm 0.02$ ,  $b = 9.959 \pm 0.006$  and  $c = 5.607 \pm 0.005$  Å;  $\beta$ -Cs<sub>3</sub>GaF<sub>6</sub> is also orthorhombic,  $a = 10.356 \pm 0.003$ ,  $b = 8.280 \pm 0.003$ ,  $c = 7.621 \pm 0.005$  Å;  $\gamma$ -Cs<sub>3</sub>GaF<sub>6</sub> is tetragonal,  $a = 6.833 \pm 0.003$ ,  $c = 9.869 \pm 0.002$  Å; CsGaF<sub>4</sub> is orthorhombic,  $a = 8.571 \pm 0.007$ ,  $b = 7.575 \pm 0.007$  and  $c = 6.981 \pm 0.006$  Å. © 2000 Elsevier Science B.V. All rights reserved.

*Keywords:* RbF; CsF; GaF<sub>3</sub>; Phase diagram; Aluminum brazing

## 1. Introduction

The systems RbF–GaF<sub>3</sub> and CsF–GaF<sub>3</sub> have been investigated by Chassaing [1]. Minimal eutectic were located at 43 mol% at 548°C and 45 mol% at 500°C of GaF<sub>3</sub> in respective systems were determined. A system of type similar to that of RbF–AlF<sub>3</sub> and CsF–AlF<sub>3</sub> [2,3], along with their lower temperature of eutectics suggested at these compositions as a flux used in Nocolok method [4] for brazing aluminum and its alloys. But we could not repeat the reported temperatures of Chassaing. So we decided to re-study these two systems.

## 2. Experimental

### 2.1. Preparation of GaF<sub>3</sub>

A certain amount of Ga metal with purity > 99.99% was reacted with excessive hydrofluoric acid in a polyvinyl beaker protected with N<sub>2</sub> flow. The beaker was heated on a water-bath. H<sub>2</sub>O<sub>2</sub> was gradually dropped into the blend under continuous stirring. As the reaction was completed the product was vaporized until dry on the water-bath. The white crystal hydrate GaF<sub>3</sub>·xH<sub>2</sub>O was obtained. The GaF<sub>3</sub>·xH<sub>2</sub>O was put into a platinum crucible which was heated at 200°C for 2 h under HF-flow protection. The white mass obtained was confirmed as anhydrous GaF<sub>3</sub> by X-ray diffraction analysis.

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## 2.2. Preparation of the samples

Samples were prepared from GaF<sub>3</sub> which was placed in a platinum crucible blending with a HF solution of RbF or CsF with known concentration and content. Twenty-three samples of RbF–GaF<sub>3</sub> and 18 samples of CsF–GaF<sub>3</sub> mixtures were prepared in this way and gradually heated until dry at 200°C, then annealed for 48 h at a higher temperature such that no melting of any phase could occur. During the annealing process, grinding and mixing of the samples were repeatedly carried out in order to obtain homogeneous and equilibrium samples.

## 2.3. Differential thermal analysis

The high-temperature DTA equipment used (of the CR-G type, Beijing Optical Instruments, Inc.) was employed and calibrated using standard substances with known melting points. Both heating and cooling curves were calibrated. Al<sub>2</sub>O<sub>3</sub> was used as a reference. The heating rate was 15 min. Temperatures were determined by the heating curve, and the cooling curve also was used to correct the liquidus temperature. Experiments were conducted in dry air (relative humidity <30%) in the static state. The error in measuring temperature was ± 3°C.

## 2.4. X-ray powder diffraction analysis

The intermediate compounds in the system were determined by X-ray diffractometry (XRD, Model D<sub>max</sub> 2400, Rigaku Co., Tokyo, Japan) under CuK<sub>α</sub> radiation, with a nickel filter and λ = 1.5409.

## 3. Results and discussion

### 3.1. System RbF–GaF<sub>3</sub>

Phase diagram of the system RbF–GaF<sub>3</sub>, based on DTA data is shown in Fig. 1. The invariant data is presented in Table 1.

Fig. 1 reveals three intermediate compounds formed in the system RbF–GaF<sub>3</sub>:

1. Rb<sub>3</sub>GaF<sub>6</sub> congruently melts at 860°C and transforms from α to β form at 388°C. The compound

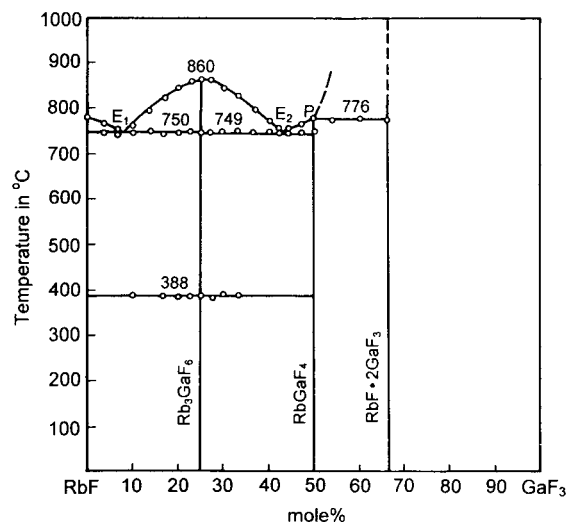


Fig. 1. Phase diagram of system RbF–GaF<sub>3</sub>.

reacts with RbF to form eutectic E<sub>1</sub> at 750°C in the location of 8.5 mol% GaF<sub>3</sub>.

2. RbGaF<sub>4</sub> peritectic melts at 776°C and reacts with Rb<sub>3</sub>GaF<sub>6</sub> to form E<sub>2</sub> at 749°C and in the location of 43.0 mol% GaF<sub>3</sub>.
3. The existence of RbF·2GaF<sub>3</sub> is identified by X-ray diffraction powder analysis. Its formation temperature was at least over 900°C has not been determined yet.

All these compounds were identified and indexed by X-ray diffraction analysis. The diffraction data of α-Rb<sub>3</sub>GaF<sub>6</sub> coincided with JCDPS(22–1275). Due to the data too complicated, the indexed result could not be successfully obtained. XRD data of β-Rb<sub>3</sub>GaF<sub>6</sub> listed in Table 2 was indexed as tetragonal, the cell parameters being:  $a = 6.324 \pm 0.004$ ,  $c = 8.860 \pm 0.003$  Å. XRD data of RbGaF<sub>4</sub> are presented in Table 3. The compound is orthorhombic, with

Table 1  
Invariant points of the system RbF–GaF<sub>3</sub>

Invariant point	Temperature (°C)	GaF <sub>3</sub> (mol%)
E <sub>1</sub>	750	8.5
E <sub>2</sub>	749	43.0
P	776	50.0
m.p. (Rb <sub>3</sub> GaF <sub>6</sub> )	860	25.0

Table 2  
Indexed data of  $\beta$ -Rb<sub>3</sub>GaF<sub>6</sub><sup>a</sup>

Observed $d$ (Å)	Calculated $d$ (Å)	$hkl_0$	$h$	$k$	$l$
5.151	5.151	3	1	0	1
	3.162		2	0	0
3.151	3.151	100	1	1	2
2.572	2.576	9	2	0	2
2.239	2.236	13	2	2	0
2.218	2.215	20	0	0	4
1.812	1.816	17	2	0	4
1.575	1.574	8	2	2	4
1.414	1.414	5	4	2	0
	1.412		3	3	2
1.403	1.403	5	1	1	6
1.187	1.188	3	3	1	6

<sup>a</sup>Tetragonal cell:  $a = 6.324 \pm 0.004$ ;  $c = 8.860 \pm 0.003$  Å.Table 3  
Indexed data of RbGaF<sub>4</sub><sup>a</sup>

Observed $d$ (Å)	Calculated $d$ (Å)	$hkl_0$	$h$	$k$	$l$
4.197	4.192	13	2	0	1
4.073	4.092	15	0	2	1
3.735	3.735	9	1	0	2
3.418	3.424	54	2	2	0
3.276	3.276	23	3	0	0
2.919	2.938	43	1	2	2
2.316	3.313	17	1	4	0
	2.279		4	1	1
	2.276		3	3	0
2.271	2.274	9	1	2	3
2.197	2.194	24	3	3	1
2.102	2.106	12	4	2	1
	2.097		4	0	2
2.026	2.029	16	3	1	3
	2.008		1	3	3
2.004	2.006	14	1	4	2
1.765	1.767	6	5	0	2
1.705	1.708	18	4	4	0
1.489	1.489	8	5	4	1
1.460	1.460	28	1	6	2
	1.458		2	2	5
1.297	1.297	7	4	2	5
	1.299		2	0	6
1.265	1.265	8	4	6	2
1.149	1.149	5	6	0	5

<sup>a</sup>Orthorhombic cell:  $a = 9.821 \pm 0.006$ ;  $b = 9.517 \pm 0.005$ ;  $c = 8.060 \pm 0.006$  Å.

$a = 9.821 \pm 0.006$ ,  $b = 9.517 \pm 0.005$ ,  $c = 8.060 \pm 0.006$  Å. Compound RbF·2GaF<sub>3</sub> was also indexed (data listed in Table 4) as orthorhombic too, with  $a = 9.459 \pm 0.005$ ,  $b = 9.336 \pm 0.005$ ,  $c = 7.685 \pm 0.005$  Å.

Table 4  
Indexed data of RbF·2GaF<sub>3</sub><sup>a</sup>

Observed $d$ (Å)	Calculated $d$ (Å)	$hkl_0$	$h$	$k$	$l$
5.961	5.980	8	1	0	1
	5.941		0	1	1
4.679	4.667	3	0	2	0
	3.326		1	1	2
3.318	3.324	5	2	2	0
	2.986		3	1	0
	2.985		2	0	2
2.966	2.966	12	0	2	2
	2.957		1	3	0
2.928	2.919	15	3	0	1
2.816	2.829	34	1	2	2
2.623	2.612	23	3	2	0
2.523	2.513	23	2	2	2
2.412	2.418	10	0	3	2
2.351	2.360	15	3	1	2
	2.342		1	3	2
2.231	2.233	5	0	4	1
2.132	2.130	7	3	3	1
2.026	2.030	4	2	2	3
	2.021		2	4	1
1.971	1.967	3	4	1	2
1.922	1.922	100	0	0	4
	1.920		3	3	2
1.890	1.892	3	5	0	0
1.840	1.840	3	2	4	2
	1.836		5	0	1
	1.826		2	3	3
1.823	1.823	3	3	4	1
	1.694		2	5	1
1.692	1.691	8	4	3	2
1.665	1.663	12	2	2	4
	1.623		4	4	1
1.621	1.622	5	2	4	3
1.552	1.555	4	6	1	0
1.478	1.478	11	2	6	0
	1.466		2	0	5
1.461	1.461	15	0	2	5
	1.460		6	0	2
1.420	1.420	3	4	2	4
1.406	1.407	6	6	3	0

<sup>a</sup>Orthorhombic cell:  $a = 9.459 \pm 0.005$ ;  $b = 9.336 \pm 0.005$ ;  $c = 7.685 \pm 0.005$  Å.

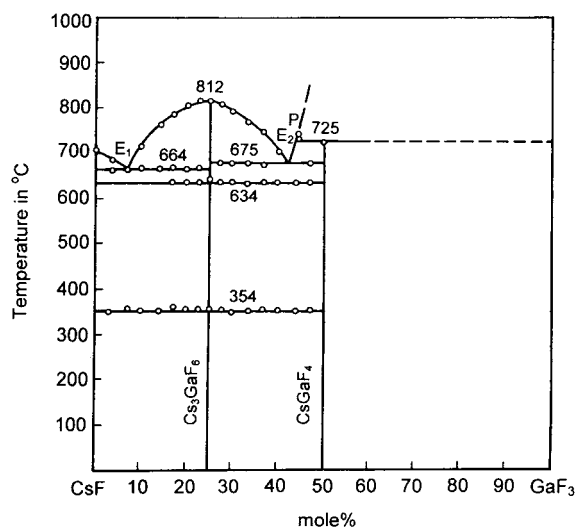


Fig. 2. Phase diagram for the system CsF–GaF<sub>3</sub>.

### 3.2. System CsF–GaF<sub>3</sub>

The phase diagram of the CsF–GaF<sub>3</sub> system, based on the results of DTA is displayed in Fig. 2. Invariant points can be seen in Table 5.

Fig. 2 reveals two intermediate compounds formed in the system.

1. Cs<sub>3</sub>GaF<sub>6</sub> congruently melts at 812°C and transforms from  $\alpha$  to  $\beta$  and  $\gamma$  form at 354°C and 634°C, respectively. Cs<sub>3</sub>GaF<sub>6</sub> reacts with CsF to form eutectic E<sub>1</sub> at 664°C in the location of 7.5 mol% GaF<sub>3</sub>.
2. Peritectic reaction of CsGaF<sub>4</sub> takes place at 725°C. The compound reacts with Cs<sub>3</sub>GaF<sub>6</sub> to form eutectic E<sub>2</sub> at 675°C and in the position of 44.0 mol% GaF<sub>3</sub>.

A technique of quenching in liquid N<sub>2</sub> flow was used to keep the structure for determining the sample by X-ray diffractometry.

Table 5  
Invariant points of the system CsF–GaF<sub>3</sub>

Invariant point	Temperature (°C)	GaF <sub>3</sub> (mol%)
E <sub>1</sub>	664	7.5
E <sub>2</sub>	675	42.0
P	725	44.0
m.p. (Cs <sub>3</sub> GaF <sub>6</sub> )	812	25.0

$\alpha$ -Cs<sub>3</sub>GaF<sub>6</sub> was indexed as orthorhombic with  $a = 10.62 \pm 0.02$ ,  $b = 9.959 \pm 0.006$ , and  $c = 5.607 \pm 0.005$  Å;  $\beta$ -Cs<sub>3</sub>GaF<sub>6</sub> is also orthorhombic with  $a = 10.356 \pm 0.003$ ,  $b = 8.280 \pm 0.003$ ,  $c = 7.621 \pm 0.005$  Å;  $\gamma$ -Cs<sub>3</sub>GaF<sub>6</sub> is tetragonal with  $a = 6.833 \pm 0.003$ ,  $c = 9.869 \pm 0.002$  Å. The indexed results of these compounds are listed in Tables 6–8.

CsGaF<sub>4</sub> was indexed (see Table 9) by X-ray diffraction as orthorhombic with  $a = 8.571 \pm 0.007$ ,  $b = 7.575 \pm 0.007$  and  $c = 6.981 \pm 0.006$  Å.

Except for two compounds Rb<sub>3</sub>GaF<sub>6</sub> (Cs<sub>3</sub>GaF<sub>6</sub>) and RbGaF<sub>4</sub> (CsGaF<sub>4</sub>) being only commonly recognized, these re-investigated phase diagrams are quite different from that reported in Chassaing's research. The compounds Rb<sub>2</sub>GaF<sub>5</sub> and Rb<sub>2</sub>Ga<sub>5</sub>F<sub>17</sub> in system RbF–GaF<sub>3</sub>, Cs<sub>5</sub>Ga<sub>3</sub>F<sub>14</sub> and CsGa<sub>2</sub>F<sub>7</sub> in the system CsF–GaF<sub>3</sub> reported by Chassaing, could not confirm their existence in this research. Another compound RbF·2GaF<sub>3</sub> was indexed in our research but no infor-

Table 6  
Indexed data of  $\alpha$ -Cs<sub>3</sub>GaF<sub>6</sub><sup>a</sup>

Observed $d$ (Å)	Calculated $d$ (Å)	$hkl_0$	$h$	$k$	$l$
4.993	4.985	36	0	2	0
	4.960		1	0	1
4.447	4.436	43	1	1	1
3.743	3.720	35	0	2	1
3.594	3.601	34	2	1	1
	3.336		3	1	0
3.312	3.323	84	0	3	0
	2.712		1	0	2
2.700	2.696	27	0	1	2
2.608	2.612	21	1	1	2
2.428	2.427	21	1	4	0
	2.421		3	3	0
2.342	2.342	33	4	2	0
	2.331		4	1	1
1.930	1.931	21	4	0	2
1.911	1.912	29	3	4	1
1.653	1.652	18	3	0	3
1.641	1.641	100	1	6	0
	1.481		1	4	3
	1.480		6	1	2
1.479	1.479	16	3	3	3
1.392	1.391	16	1	0	4
	1.335		2	7	1
1.333	1.333	15	7	0	2

<sup>a</sup>Orthorhombic cell:  $a = 10.62 \pm 0.02$ ;  $b = 9.959 \pm 0.006$ ;  $c = 5.607 \pm 0.005$  Å.

Table 7  
Indexed data of  $\beta$ -Cs<sub>3</sub>GaF<sub>6</sub><sup>a</sup>

Observed <i>d</i> (Å)	Calculated <i>d</i> (Å)	<i>h</i> / <i>k</i> / <i>l</i>	<i>h</i>	<i>k</i>	<i>l</i>
5.157	5.180	26	2	0	0
3.639	3.644	6	0	2	1
3.581	3.575	9	1	0	2
3.466	3.463	4	0	1	2
	3.451		3	0	0
3.411	3.410	6	1	2	1
3.300	3.288	100	1	1	2
3.140	3.145	15	3	0	1
3.083	3.066	5	2	0	2
2.693	2.704	11	1	2	2
2.595	2.597	4	0	3	1
	2.590		4	0	0
	2.453		4	0	1
2.442	2.446	4	3	1	2
	2.434		2	3	0
2.328	2.324	18	2	3	1
2.151	2.154	5	3	3	0
1.922	1.922	26	2	4	0
	1.905		0	0	4
1.902	1.902	18	4	2	2
1.856	1.857	4	0	1	4
	1.852		5	2	0
1.826	1.827	4	1	1	4
	1.819		5	0	2
1.817	1.818	4	0	4	2
	1.816		4	0	3
1.799	1.799	4	5	2	1
1.780	1.776	4	5	1	2
1.770	1.771	4	4	1	3
1.730	1.730	3	0	2	4
1.730	1.729	5	3	4	1
	1.726		6	0	0
1.649	1.649	6	6	1	1
	1.640		2	2	4
1.638	1.636	4	3	1	4
	1.636		1	5	0
1.478	1.478	4	7	0	0
1.473	1.471	7	6	2	2
1.358	1.358	4	0	6	1
1.246	1.247	16	1	1	6

<sup>a</sup>Orthorhombic cell:  $a = 10.356 \pm 0.003$ ;  $b = 8.280 \pm 0.003$ ;  $c = 7.621 \pm 0.005$  Å.

mation was indicated in the Chassaing's report. The difference in our study is that the original material GaF<sub>3</sub> was prepared from super-pure metal gallium and the samples used for DTA analysis were prepared by total solution synthesis. This, we believe, may be the best way for preparing the real homogeneous and equilibrium samples.

Table 8  
Indexed data of  $\gamma$ -Cs<sub>3</sub>GaF<sub>6</sub><sup>a</sup>

Observed <i>d</i> (Å)	Calculated <i>d</i> (Å)	<i>h</i> / <i>k</i> / <i>l</i>	<i>h</i>	<i>k</i>	<i>l</i>
3.288	3.287	47	0	0	3
3.054	3.070	11	2	1	0
2.966	2.966	15	1	0	3
2.919	2.930	12	2	1	1
2.740	2.724	7	1	1	3
2.321	2.321	10	1	0	4
1.920	1.924	100	2	1	4
1.898	1.897	12	1	0	5
	1.600		1	0	6
1.599	1.599	6	3	3	1
1.520	1.518	6	4	2	1

<sup>a</sup>Tetragonal cell:  $a = 6.833 \pm 0.003$ ;  $c = 9.869 \pm 0.002$  Å.

Table 9  
Indexed data of CsGaF<sub>4</sub><sup>a</sup>

Observed <i>d</i> (Å)	Calculated <i>d</i> (Å)	<i>h</i> / <i>k</i> / <i>l</i>	<i>h</i>	<i>k</i>	<i>l</i>
3.645	3.647	26	2	0	1
3.336	3.330	15	0	2	1
3.306	3.290	100	2	1	1
2.829	3.837	23	2	2	0
2.704	2.704	22	2	0	2
2.527	2.526	20	0	3	0
2.328	2.328	27	0	0	3
1.907	1.908	25	3	2	2
1.646	1.646	8	4	2	2
1.461	1.461	16	3	1	4
	1.460		1	5	1

<sup>a</sup>Orthorhombic cell:  $a = 8.571 \pm 0.007$ ;  $b = 7.575 \pm 0.007$ ;  $c = 6.981 \pm 0.006$  Å.

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